NSN 5961-01-139-0332

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View Online at https://aerobasegroup.com/nsn/5961-01-139-0332 **Inclosure Material:** Metal **Overall Length:** 0.328 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:**

Silicon

Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 10.00 amperes source cutoff current and 25.00 amperes source cutoff current

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

1 case and 2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/509 government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

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